

Features

- **Bipolar Speed**
Read Access Time - 35 ns
- **Low Power CMOS Operation**
25 mA max. Standby
45 mA max. Active at 10 MHz
- **Direct Bipolar PROM Replacement**
- **High Output Drive Capability**
- **Reprogrammable - 100 μ s/byte (typical)**
Tested 100% for Programmability
- **JEDEC Approved Byte-Wide Pinout**
300-mil DIP, 600-mil DIP and LCC packages
- **CMOS and TTL Compatible Inputs and Outputs**
- **High Reliability Latch-Up Resistant CMOS Technology**
- **Integrated Product Identification Code**
- **Full Military, Industrial and Commercial Temperature Ranges**
- **Fully Compatible with AT27HC641/2**

**64K (8K x 8)
Reprogrammable
CMOS
PROM**

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Description

The AT27HC641R/642R chip family is a high-speed, low-power 65,536 bit reprogrammable read only memory (PROM), which is UV erasable, organized as 8K x 8 bits. All devices require only one 5 V power supply in normal read mode operation. All bytes on the 641R and 642R parts can be accessed in less than 35 ns, making these parts ideal for high-performance systems without penalizing bit density or power consumption.

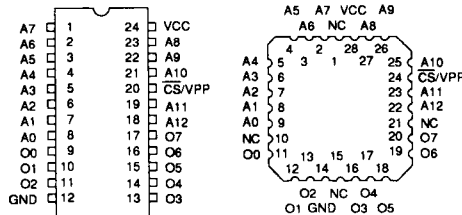
The 640R series of devices come in a choice of JEDEC-approved 24-pin DIP or 28-pad LCC packages, providing a direct power saving CMOS upgrade for systems originally using Bipolar PROMs. The AT27HC641R is available in a standard 600-mil cerdip or one-time programmable plastic (OTP) package, and LCC package, while the AT27HC642R is available in a space-saving 300-mil cerdip or plastic (OTP) package.

Atmel's 1.2-micron, high-speed CMOS technology provides optimum speed, low-power and high noise immunity. Power consumption on the AT27HC641 and AT27HC642 is typically only 30 mA in Active Mode and less than 10 mA in Standby. The high speed CMOS process is an extension of Atmel's high quality and highly manufacturable floating poly PROM technology. The ability to reprogram the PROM, which is fully tested before shipment, provides inherently better programmability and reliability than one-time fusible PROMs.

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Pin Configurations

Pin Name	Function
A0-A12	Addresses
CS/V _{PP}	Chip Select/V _{PP}
O0-O7	Outputs



Description (Continued)

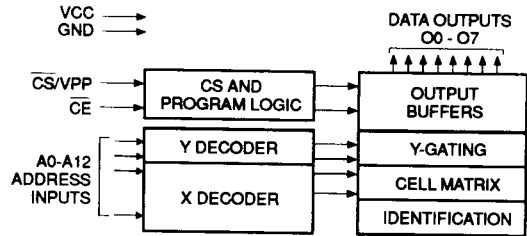
With a storage capacity of 8K bytes, Atmel's 640R series parts allow firmware to be stored reliably and to be accessed at bipolar PROM speeds. All the 640R series parts have exceptional output drive capability - source 4 mA and sink 16 mA per output.

Atmel's 640R series chips also have additional features to ensure high-quality and efficient production use. The Rapid programming algorithm reduces the time required to program the chip and guarantees reliable programming. The Integrated Product Identification Code electronically identifies the device and manufacturing origin. This feature is used by industry standard programming equipment to select the proper programming algorithms and voltages.

Erase Characteristics

The entire memory array of an Atmel 640R series chip is erased (all outputs read as V_{OH}) after exposure to ultraviolet light at a wavelength of 2537Å. Complete erasure is assured after a minimum of 20 minutes exposure using 12,000 $\mu\text{W}/\text{cm}^2$ intensity lamps spaced one inch away from the chip. Minimum erase time for lamps at other intensity ratings can be calculated from the minimum integrated erasure dose of 15W-sec/cm². To prevent unintentional erasure, an opaque label is recommended to cover the clear window on any PROM which will be subjected to continuous fluorescent indoor lighting or sunlight.

Block Diagram



Absolute Maximum Ratings*

Temperature Under Bias	-55°C to +125°C
Storage Temperature	-65°C to +150°C
Voltage on Any Pin with Respect to Ground.....	-2.0 V to +7.0 V ⁽¹⁾
Voltage on A9 with Respect to Ground	-2.0 V to +14.0 V ⁽¹⁾
$\overline{\text{CS}}/\text{V}_{\text{PP}}$ Supply Voltage with Respect to Ground.....	-2.0 V to +14.0 V ⁽¹⁾
Integrated UV Erase Dose	7258 W-sec/cm ²

*NOTICE: Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Notes:

1. Minimum voltage is -0.6 V dc which may undershoot to -2.0 V for pulses of less than 20 ns. Maximum output pin voltage is $V_{\text{CC}}+0.75$ V dc which may overshoot to +7.0 V for pulses of less than 20 ns.

Operating Modes

MODE \ PIN	$\overline{\text{CS}}/\text{V}_{\text{PP}}$	Ai	VCC	Outputs
Read	V_{IL}	Ai	VCC	DOUT
Standby	V_{IH}	X ⁽¹⁾	VCC	High Z
Rapid Program ⁽²⁾	VPP	Ai	VCC	DIN
PGM Verify	V_{IL}	Ai	VCC	DOUT
Product Identification ⁽⁴⁾	V_{IL}	A9= V_{H} ⁽³⁾ A0= V_{IH} or V_{IL} A1-A12= V_{IL}	VCC	Identification Code

- Notes:
1. X can be V_{IL} or V_{IH} .
 2. Refer to Programming characteristics.
 3. $V_{\text{IH}} = 12.0 \pm 0.5$ V.

4. Two identifier bytes may be selected. All Ai inputs are held low (V_{IL}), except A9 which is set to V_{H} and A0 which is toggled low (V_{IL}) to select the Manufacturer's Identification byte and high (V_{IH}) to select the Device Code byte.

D.C. and A.C. Operating Conditions for Read Operation

AT27HC641R / AT27HC642R						
		-35	-45	-55	-70	-90
Operating Temperature (Case)	Com.	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C	0°C - 70°C
	Ind.		-40°C - 85°C	-40°C - 85°C	-40°C - 85°C	-40°C - 85°C
	Mil.		-55°C - 125°C	-55°C - 125°C	-55°C - 125°C	-55°C - 125°C
V _{CC} Power Supply		5 V ± 5%	5 V ± 10%	5 V ± 10%	5 V ± 10%	5 V ± 10%

D.C. and Operating Characteristics for Read Operation

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Symbol	Parameter	Condition	Min	Max	Units
I _{LI}	Input Load Current	V _{IN} = -0.1 V to V _{CC} +1 V		10	μA
I _{LO}	Output Leakage Current	V _{OUT} = -0.1 V to V _{CC} +0.1 V		10	μA
I _{PP1}	CS/V _{PP} ⁽¹⁾ Read/Standby Current	CS/V _{PP} = -0.1 V to V _{CC} +1 V		10	μA
I _{SB}	V _{CC} ⁽¹⁾ Standby Current	I _{SB1} (CMOS) CS/V _{PP} = V _{CC} -0.3 to V _{CC} +1.0 V	Com.	25	mA
			Ind.,Mil.	30	mA
		I _{SB2} (TTL) CS/V _{PP} = 2.0 to V _{CC} +1.0 V	Com.	25	mA
			Ind.,Mil.	30	mA
I _{CC}	V _{CC} Active Current	f = 10 MHz, I _{OUT} = 0 mA, CS/V _{PP} = V _{IL}	Com.	45	mA
			Ind.,Mil.	50	mA
I _{OS} ⁽²⁾	Output Short Circuit Current	V _{OUT} = 0 V		-100	mA
V _{IL}	Input Low Voltage		-0.6	0.8	V
V _{IH}	Input High Voltage		2.0	V _{CC} +0.75	V
V _{OL}	Output Low Voltage	I _{OL} = 16 mA		.4	V
V _{OH}	Output High Voltage	I _{OH} = -100 μA		V _{CC} -0.3	V
		I _{OH} = -4.0 mA		2.4	V

Notes: 1. V_{CC} must be applied simultaneously or before CS/V_{PP}, and removed simultaneously or after CS/V_{PP}.

2. Not more than one output at a time should be shorted. Duration of short circuit test should not exceed 30 sec. This parameter is only sampled and is not 100% tested. See Absolute Maximum Ratings.

A.C. Characteristics for Read Operation

			AT27HC641R / AT27HC642R										
			-35		-45		-55		-70		-90		Units
Symbol	Parameter		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t _{AA} ⁽⁴⁾	Address to Output Delay	Com.		35		45		55		70		90	ns
		Ind.,Mil				45		55		70		90	ns
t _{CS} ^(2,4)	CS/V _{PP} to Output Delay			25		30		35		45		55	ns
t _{CD} ^(3,4,5)	CS/V _{PP} to Output Float		0	25	0	30	0	35	0	40	0	45	ns

Notes: 2, 3, 4, 5. - see AC Waveforms for Read Operation.



D.C. Programming Characteristics

T_A = 25 ± 5°C, V_{CC} = 6.5 ± 0.25 V, \overline{CS}/V_{PP} = 13.0 ± 0.25 V

Symbol	Parameter	Test Conditions	Limits		Units
			Min	Max	
I _{LI}	Input Load Current	V _{IN} = V _{IL} , V _{IH}		10	μA
V _{IL}	Input Low Level	(All Inputs)	-0.6	0.8	V
V _{IH}	Input High Level		2.0	V _{CC} - 1	V
V _{OL}	Output Low Volt.	I _{OL} = 16 mA		.4	V
V _{OH}	Output High Volt.	I _{OH} = -4.0 mA	2.4		V
I _{CC2}	V _{CC} Supply Current (Program and Verify)			50	mA
I _{PP2}	\overline{CS}/V_{PP} Supply Current	$\overline{CS}/V_{PP} = V_{PP}$		30	mA
V _{ID}	A9 Product Identification Voltage		11.5	12.5	V

A.C. Programming Characteristics

T_A = 25 ± 5°C, V_{CC} = 6.5 ± 0.25 V, \overline{CS}/V_{PP} = 13.0 ± 0.25 V

Symbol	Parameter	Test Conditions* (see Note 1)	Limits		Units
			Min	Max	
t _{AS}	Address Setup Time		2		μs
t _{CSS}	\overline{CS}/V_{PP} Setup Time		2		μs
t _{DS}	Data Setup Time		2		μs
t _{AH}	Address Hold Time		0		μs
t _{DH}	Data Hold Time		2		μs
t _{DFP}	\overline{CS}/V_{PP} High to Output Float Delay	(Note 2)	0	130	ns
t _{VCS}	V _{CC} Setup Time		2		μs
t _{PW}	\overline{CS}/V_{PP} Program Pulse Width	(Note 3)	95	105	μs
t _{CS}	Data Valid from \overline{CS}/V_{PP}			70	ns

*A.C. Conditions of Test:

- Input Rise and Fall Times (10% to 90%) 5 ns
- Input Pulse Levels 0.0 V to 3.0 V
- Input Timing Reference Level 1.5 V
- Output Timing Reference Level 1.5 V

Notes:

1. V_{CC} must be applied simultaneously or before \overline{CS}/V_{PP} and removed simultaneously or after \overline{CS}/V_{PP} .
2. This parameter is only sampled and is not 100% tested. Output Float is defined as the point where data is no longer driven — see timing diagram.
3. Program Pulse width tolerance is 100 μsec ± 5%.

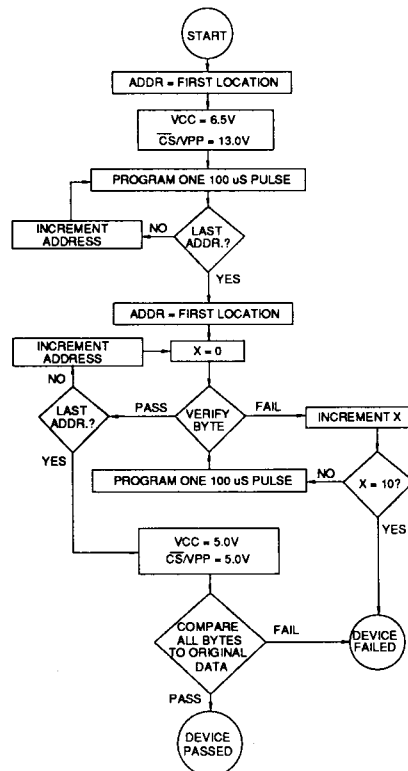
Atmel's 27HC641R/2R Integrated Product Identification Code

Codes	Pins								Hex Data	
	A0	O7	O6	O5	O4	O3	O2	O1		O0
Manufacturer	0	0	0	0	1	1	1	1	0	1E
Device Type	1	0	0	0	1	0	0	0	0	10

Rapid Programming Algorithm

A 100 μs \overline{CS}/V_{PP} pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5 V and \overline{CS}/V_{PP} is raised to 13.0 V. Each address is first programmed with one 100 μs \overline{CS}/V_{PP} pulse without verification. Then a verification / re-programming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive 100 μs pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. \overline{CS}/V_{PP} is then lowered to 5.0 V and V_{CC} to 5.0 V. All bytes are read again and compared with the original data to determine if the device passes or fails.

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Ordering Information

t _{ACC} (ns)	I _{CC} (mA)		Ordering Code	Package	Operation Range
	Active	Standby			
35	45	25	AT27HC641R-35DC	24DW6	Commercial (0°C to 70°C)
			AT27HC642R-35DC	24DW3	
			AT27HC641R-35LC	28LW	
45	45	25	AT27HC641R-45DC	24DW6	Commercial (0°C to 70°C)
			AT27HC642R-45DC	24DW3	
			AT27HC641R-45LC	28LW	
			AT27HC641R-45PC	24P6	
			AT27HC642R-45PC	24P3	
45	50	30	AT27HC641R-45DI	24DW6	Industrial (-40°C to 85°C)
			AT27HC642R-45DI	24DW3	
			AT27HC641R-45LI	28LW	
		AT27HC641R-45PI	24P6	Military (-55°C to 125°C)	
		AT27HC642R-45PI	24P3		
		AT27HC641R-45DM	24DW6		
AT27HC642R-45DM	24DW3	Military/883C Class B, Fully Compliant (-55°C to 125°C)			
AT27HC641R-45LM	28LW				
55	45	25	AT27HC641R-55DC	24DW6	Commercial (0°C to 70°C)
			AT27HC642R-55DC	24DW3	
			AT27HC641R-55LC	28LW	
			AT27HC641R-55PC	24P6	
			AT27HC642R-55PC	24P3	
55	50	30	AT27HC641R-55DI	24DW6	Industrial (-40°C to 85°C)
			AT27HC642R-55DI	24DW3	
			AT27HC641R-55LI	28LW	
		AT27HC641R-55PI	24P6	Military (-55°C to 125°C)	
		AT27HC642R-55PI	24P3		
		AT27HC641R-55DM	24DW6		
AT27HC642R-55DM	24DW3	Military/883C Class B, Fully Compliant (-55°C to 125°C)			
AT27HC641R-55LM	28LW				
70	45	25	AT27HC641R-70DC	24DW6	Commercial (0°C to 70°C)
			AT27HC642R-70DC	24DW3	
			AT27HC641R-70LC	28LW	
			AT27HC641R-70PC	24P6	
70	50	30	AT27HC641R-70DI	24DW6	Industrial (-40°C to 85°C)
			AT27HC642R-70DI	24DW3	
			AT27HC641R-70LI	28LW	
			AT27HC641R-70PI	24P6	
			AT27HC642R-70PI	24P3	

Ordering Information

tACC (ns)	Icc (mA)		Ordering Code	Package	Operation Range
	Active	Standby			
70	50	30	AT27HC641R-70DM AT27HC642R-70DM AT27HC641R-70LM	24DW6 24DW3 28LW	Military (-55°C to 125°C)
			AT27HC641R-70DM/883 AT27HC642R-70DM/883 AT27HC641R-70LM/883	24DW6 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)
90	45	25	AT27HC641R-90DC AT27HC642R-90DC AT27HC641R-90LC AT27HC641R-90PC AT27HC642R-90PC	24DW6 24DW3 28LW 24P6 24P3	Commercial (0°C to 70°C)
90	50	30	AT27HC641R-90DI AT27HC642R-90DI AT27HC641R-90LI AT27HC641R-90PI AT27HC642R-90PI	24DW6 24DW3 28LW 24P6 24P3	Industrial (-40°C to 85°C)
			AT27HC641R-90DM AT27HC642R-90DM AT27HC641R-90LM	24DW6 24DW3 28LW	Military (-55°C to 125°C)
			AT27HC641R-90DM/883 AT27HC642R-90DM/883 AT27HC641R-90LM/883	24DW6 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)
45	50	30	5962-87515 01 JX 5962-87515 01 KX 5962-87515 01 LX 5962-87515 01 3X	24DW6 24CW 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)
55	50	30	5962-87515 02 JX 5962-87515 02 KX 5962-87515 02 LX 5962-87515 02 3X	24DW6 24CW 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)
70	50	30	5962-87515 03 JX 5962-87515 03 KX 5962-87515 03 LX 5962-87515 03 3X	24DW6 24CW 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)
90	50	30	5962-87515 04 JX 5962-87515 04 KX 5962-87515 04 LX 5962-87515 04 3X	24DW6 24CW 24DW3 28LW	Military/883C Class B, Fully Compliant (-55°C to 125°C)

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Package Type	
24CW	24 Lead, Windowed, Ceramic Flat Package (Cerpack)
24DW3	24 Lead, 0.300" Wide, Windowed, Ceramic Dual Inline Package (Cerdip)
24DW6	24 Lead, 0.600" Wide, Windowed, Ceramic Dual Inline Package (Cerdip)
28LW	28 Pad, Windowed, Ceramic Leadless Chip Carrier (LCC)
24P3	24 Lead, 0.300" Wide, Plastic Dual Inline Package OTP (PDIP)
24P6	24 Lead, 0.600" Wide, Plastic Dual Inline Package OTP (PDIP)

